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|  | <h2 style="color: red;">IRFB812PBF</h2> | |
| | Hersteller-Teilenummer: | IRFB812PBF |
|  | Hersteller / Marke: | International Rectifier (Infineon Technologies) |
| | Teil der Beschreibung: | MOSFET N CH 500V 3.6A TO220AB |
| Datenblätter: |  IRFB812PBF.pdf | |
| RoHs Status: | Bleifrei / RoHS-konform | |
| Lagerzustand: | New original, 5040 pcs Stock Available. | |
| Liefern von: | Hong Kong | |
| Versandweg: | DHL/Fedex/TNT/UPS/EMS | |
| <p>Image may be representation. See specs for product details.</p> | | |

Spezifikationen

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|--|---|
| Teilenummer | IRFB812PBF |
| Hersteller | International Rectifier (Infineon Technologies) |
| Beschreibung | MOSFET N CH 500V 3.6A TO220AB |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 5040 pcs Stock |
| Serie | HEXFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Through Hole |
| Verpackung / Gehäuse | TO-220-3 |
| Supplier Device-Gehäuse | TO-220AB |
| Verlustleistung (max) | 78W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 500V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 3.6A (Tc) |
| Rds On (Max) @ Id, Vgs | 2.2 Ohm @ 2.2A, 10V |
| VGS (th) (Max) @ Id | 5V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 20nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 810pF @ 25V |
| Verpackung | Tube |




IRFB812PBF ist neu im Original, Suche IRFB812PBF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFB812PBF International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IRFB812PBF: Info@Y-IC.com

Sie können auch interessiert sein:

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|---|---|---|--|
|  <p>IRFB812TRPBF VB IRFB812TRPBF VB</p> |  <p>IRFB7746PBF International Rectifier (Infineon Technologies) MOSFET N-CH 75V 59A TO220</p> |  <p>IRFB7N60C3PBF IR IRFB7N60C3PBF IR</p> |  <p>IRFB9N30APBF Electro-Films (EFI) / Vishay MOSFET N-CH 300V 9.3A TO-220AB</p> |
|  <p>IRFB812 IR IR TO-220</p> |  <p>IRFB7787PBF International Rectifier (Infineon Technologies) MOSFET N-CH 75V 83A TO220</p> |  <p>IRFB9N30APBF Vishay / Siliconix MOSFET N-CH 300V 9.3A TO-220AB</p> |  <p>IRFB9N30A Vishay / Siliconix MOSFET N-CH 300V 9.3A TO-220AB</p> |

heiße Teile

Mehr

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|---|---|--|---|---|
|  IRFB59N10D |  IRFB59N10DPBF |  IRFB61N15D |  IRFB61N15DPBF |  IRFB7374 |
|  IRFB7430 |  IRFB7430PBF |  IRFB7434 |  IRFB7434GPBF |  IRFB7434PBF |
|  IRFB7437GPBF |  IRFB7437PBF |  IRFB7440GPBF |  IRFB7440PBF |  IRFB7446GPBF |
|  IRFB7446PBF |  IRFB7537 |  IRFB7540 |  IRFB7545 |  IRFB7545PBF |
|  IRFB7546 |  IRFB7546PBF |  IRFB7740 |  IRFB7740PBF |  IRFB7N60C3PBF |
|  IRFB812TRPBF |  IRFB9N30A |  IRFB9N30A |  IRFB9N30APBF |  IRFB9N30APBF |
|  IRFB9N60A |  IRFB9N60A |  IRFB9N60APBF |  IRFB9N60APBF |  IRFB9N65 |
|  IRFB9N65A |  IRFB9N65A |  IRFB9N65APBF |  IRFB9N65APBF |  IRFBA1404P |
|  IRFBA1404PPBF |  IRFBA1405P |  IRFBA22N50A |  IRFBC20-030 |  IRFBC20LPBF |
|  IRFBC20LPBF |  IRFBC20PBF |  IRFBC20PBF |  IRFBC20SPBF |  IRFBC20SPBF |

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